

Audio Jack Detector and Pop Noise Control Switch

DESCRIPTION

The DG2591 is an audio jack detector and pop noise control switch IC.

When there is no ear phone detected, the DG2591 connects the microphone bias line to ground through the MIC pin. The DG2591 also gives a logic HIGH signal to the baseband controller through the OUT pin.

The DG2591 senses the DC levels at both L_Detect and GND_Detect. When an ear phone is plugged in, the voltage at both pins will go low. The DG2591 will indicate the presence of the ear phone by pulling OUT low and the MIC switch will turn off.

The DG2591 is available ultra small miniQFN6 of 1 mm x 1.2 mm size.

FEATURES

- Operates with $1.8\text{ V} \pm 5\%$
- Low quiescent current of $2\text{ }\mu\text{A}/\text{max.}$
- Integrated sense comparator for audio L of $1.4\text{ V} \pm 5\%$ threshold
- $1\text{ }\Omega/\text{max.}$ MIC bias switch provides a quick discharge and clamping
- (Integrated deglitch circuit)
- ESD Protected
 - Human body model $> 5\text{ kV}$
 - Charged device model $> 1\text{ kV}$
 - IEC 61000-4-2 air discharge $> 15\text{ kV}$
 - IEC 61000-4-2 contact discharge $> 8\text{ kV}$
- Ultra compact miniQFN6 of 1 mm x 1.2 mm
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT
HALOGEN
FREE

APPLICATIONS

- Cellular phones
- Tablet devices
- Portable media players
- Digital cameras

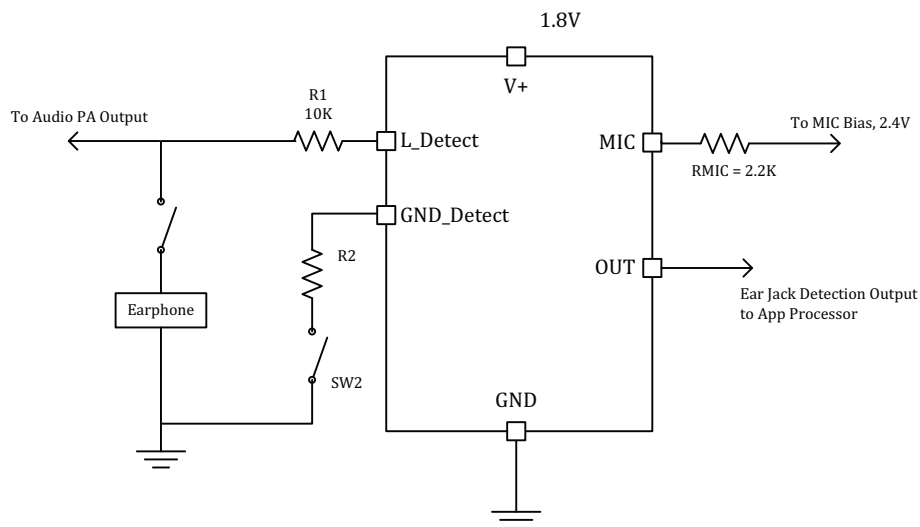


Fig. 1 - Typical Operation Circuit

PACKAGE OUTLINE

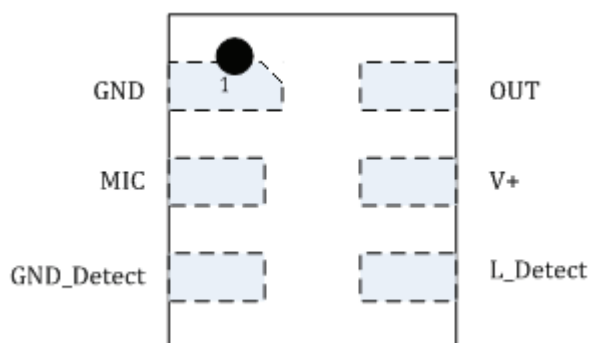
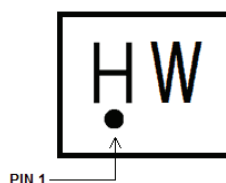


Fig. 2 - Device Pin Out miniQFN6 Top View, Pin 1 Dot Marking is on Top of the Device

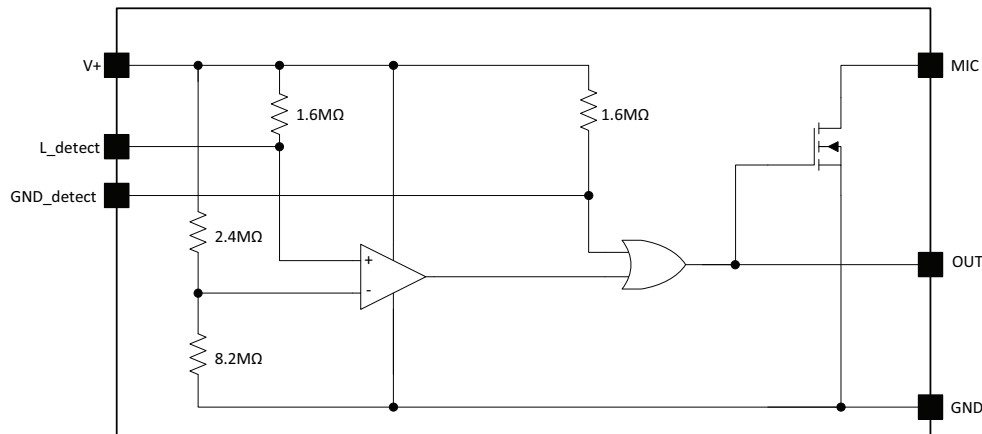
PIN DESCRIPTION		
PIN#	NAME	FUNCTION
1	GND	Ground
2	MIC	Microphone bias switch input. Connect to AUXMIC_IN
3	GND_Detect	Connect to ground detect pin at audio jack
4	L_Detect	Connected to L_Detect pin at audio jack
5	V+	Device power supply connected to 1.8 V source
6	OUT	Detect logic output connected to baseband controller

ORDERING INFORMATION		
TEMPERATURE RANGE	PACKAGE	PART NUMBER
-40 °C to 85 °C	miniQFN6	DG2591DN-T1-GE4

DEVICE MARKING



H = DG2591 Marking Code, W = Date/Lot Traceability Code


Fig. 3 - Functional Block Diagram

TRUTH TABLE			
L_DETECT	GND_DETECT	OUT	MIC
0	0	Low	High
1	x	High	Low
x	1	High	Low

ABSOLUTE MAXIMUM RATINGS				
PINS OR PARAMETERS	CONDITIONS		LIMITS	UNIT
V+	Reference to GND		-0.3 to 6	V
L_Detect, GND_Detect, OUT	Reference to GND		V+	
MIC			-0.3 to 6	
Storage Temperature			-65 to +150	°C
MSL	Moisture Sensitivity Level (JEDEC® J-STD-020)		1	Level
I _{MIC}	Switch DC current		200	mA
I _{MICPEAK}	Switch peak current (pulsed at 1 ms, < 10 % duty cycle)		500	
Latch up Current per JESD78			500	
ESD	Human body model		> 5	kV
	IEC 61000-2-4, Level 4, L_Detect, GND_Detect, MIC and GND Pins	Contact	> 8	
		Air	> 15	
	Charged device model, JESD22-C101		> 1	
RECOMMENDED OPERATING CONDITION				
V+			1.8	V
Operating Junction Temperature			-40 ~ +125	°C

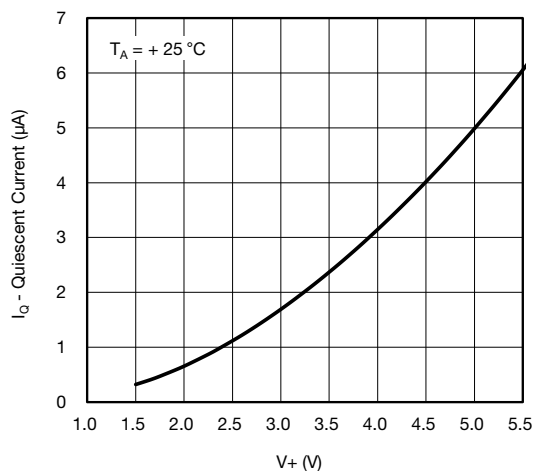
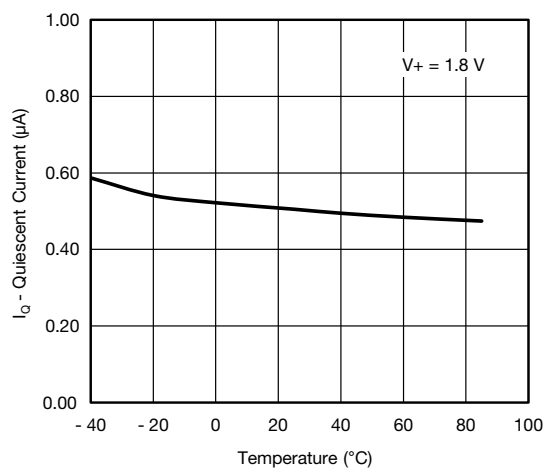
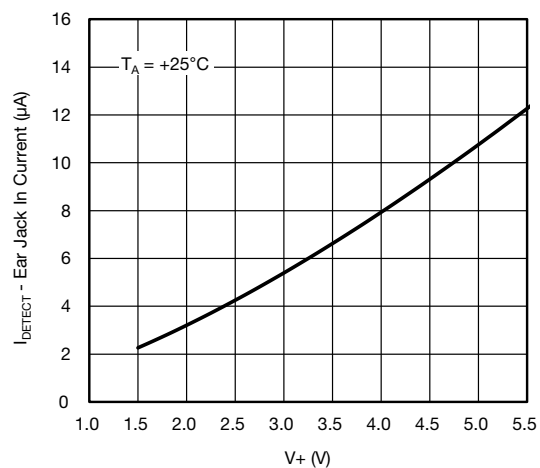
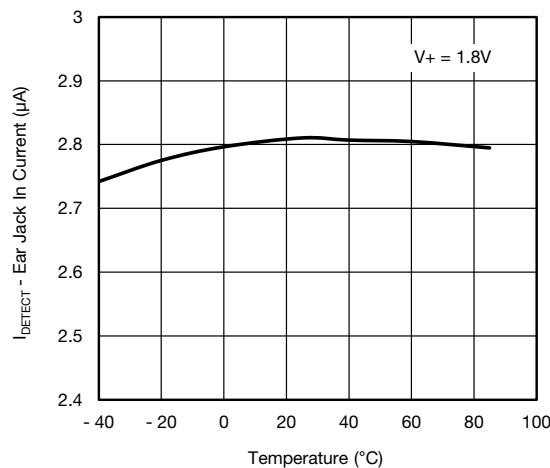
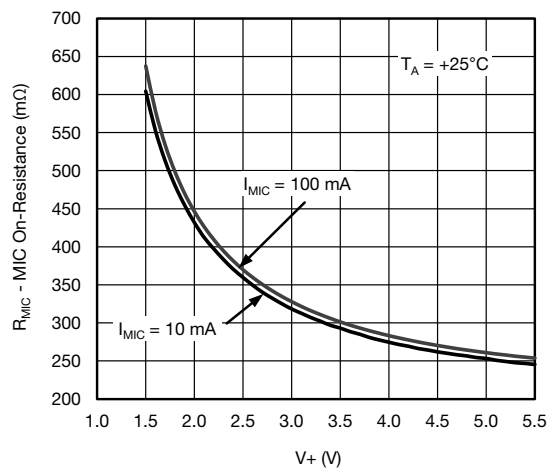
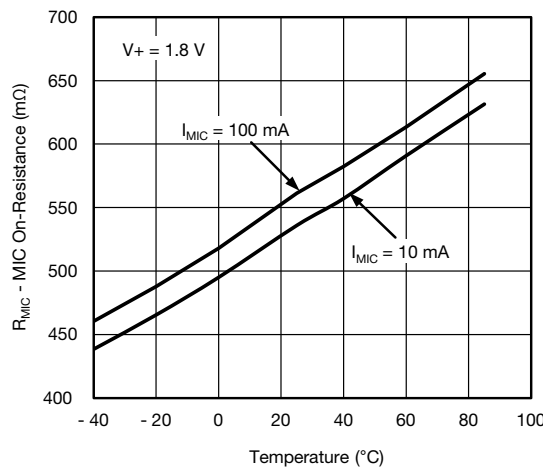
Notes

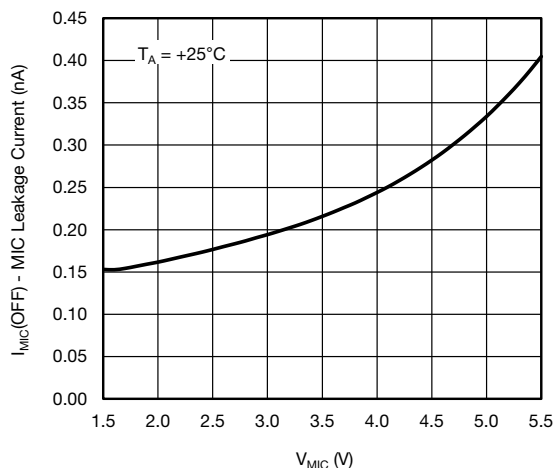
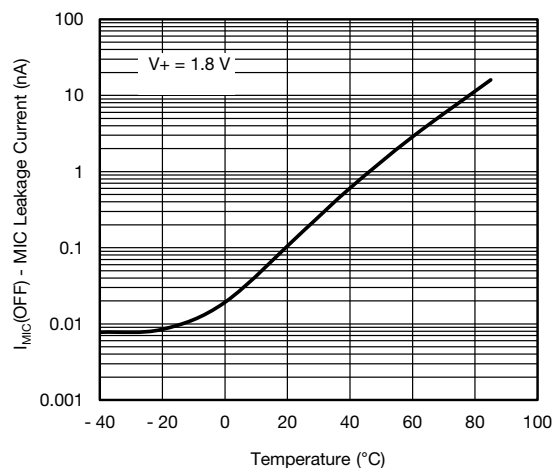
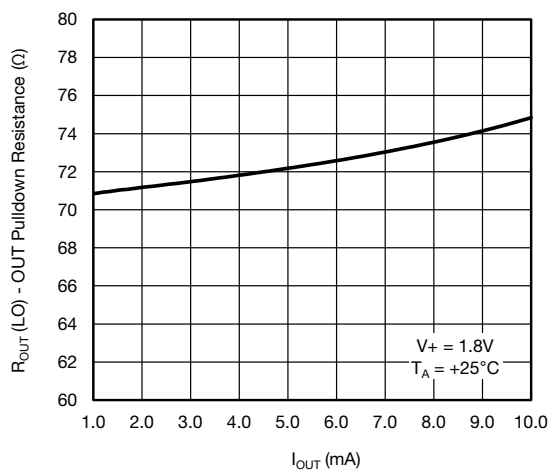
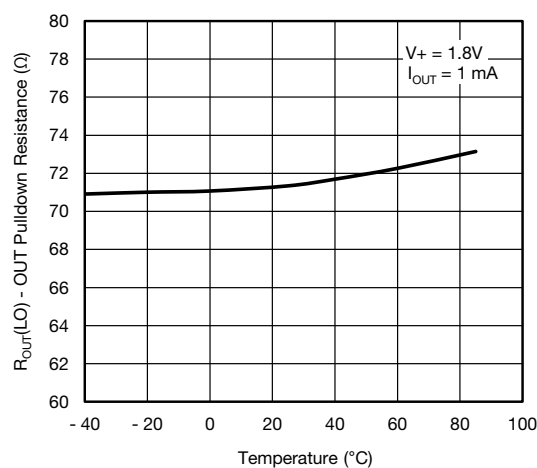
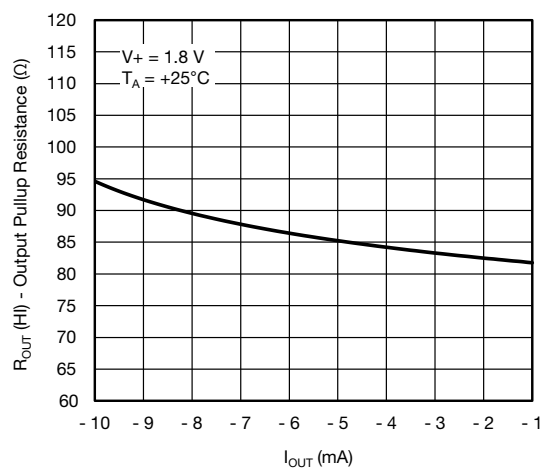
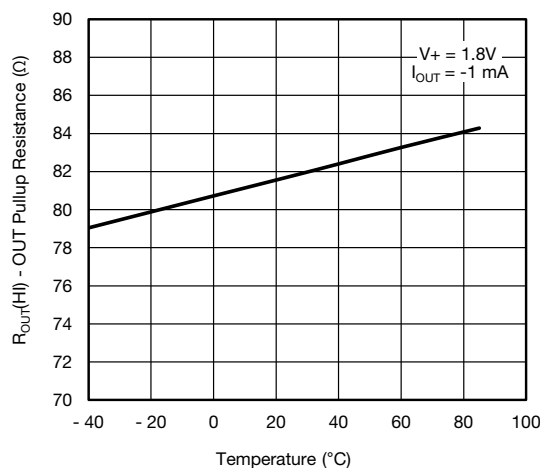
- The control logic pins should not float. It should be compliant with either high or low logic
- Negative current injection up to 300 mA

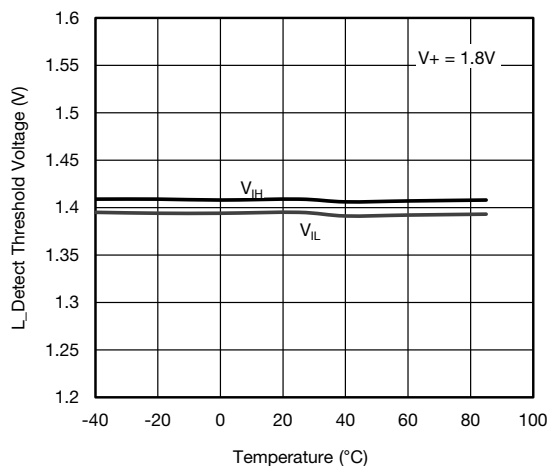
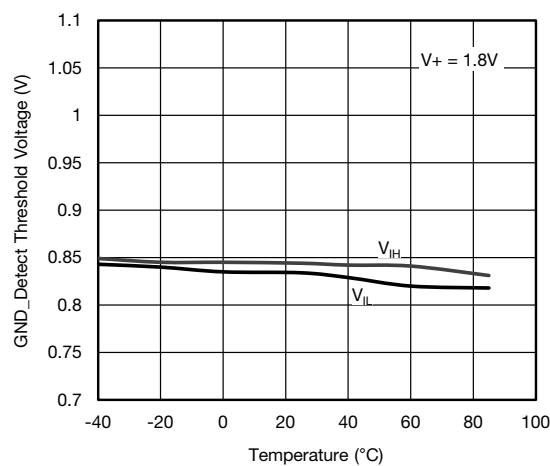
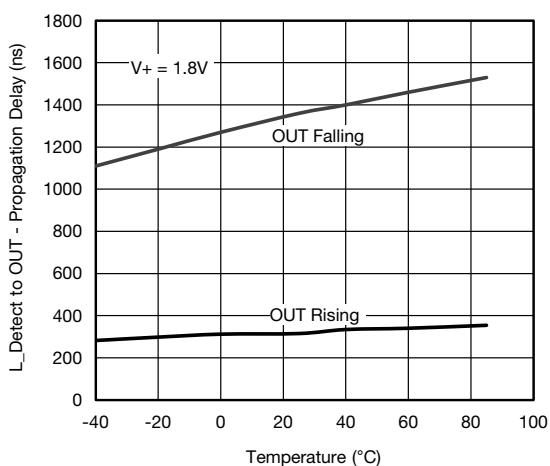
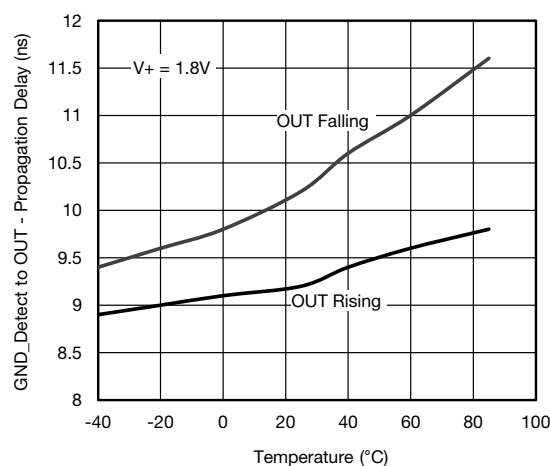
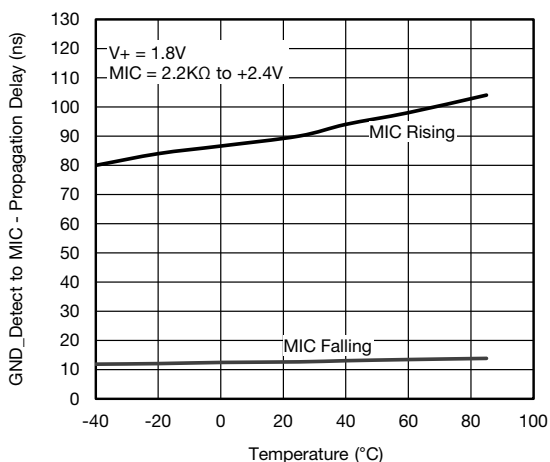
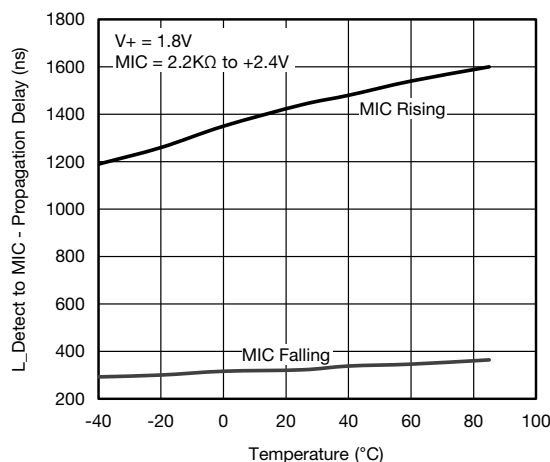
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

**ELECTRICAL CHARACTERISTICS**

PARAMETER	SYMBOL	TEST CONDITION	LIMITS			UNIT
		UNLESS OTHERWISE SPECIFIED, T _A = -40 °C to 85 °C, TYPICAL VALUES are at 25 °C	MIN.	TYP.	MAX.	
Quiescent Current	I _Q	V ₊ = 1.8 V; L_Detect, GND_Detect are open	-	< 1	2	μA
Ear Jack In Current	I _{DETECT}	V ₊ = 1.8 V; L_Detect, GND_Detect are connected with 10 kΩ to GND	-	-	5	
L_Detect Reference Voltage			1.33	1.4	1.47	V
L_Detect Reference Voltage Hysteresis		GND_Detect = 0 V	-	20	-	mV
GND_Detect Logic Low Voltage		V ₊ = 1.8 V	0.6	0.84	-	V
GND_Detect Logic High Voltage		V ₊ = 1.8 V	-	-	1.1	
MIC Switch Resistance	R _{MIC}	V ₊ = 1.8 V; I _{MIC} = 10 mA L_Detect, GND_Detect = Open	-	-	1	Ω
MIC Leakage		V _{MIC} = 2.4 V	-1	-	1	μA
OUT Pull Up Resistance	R _{OUTH}	V ₊ = 1.8 V; L_Detect, GND_Detect = Open	-	-	110	Ω
OUT Pull Down Resistance	R _{OUTL}	V ₊ = 1.8 V; L_Detect, GND_Detect are connected with 10 kΩ to GND,	-	-	100	
OUT High Logic Voltage	V _{OUTH}	V ₊ = 1.8 V; R _{OUT} = 10 kΩ L_Detect, GND_Detect = Open	1.6	-	-	V
OUT Low Logic Voltage	V _{OUTL}	V ₊ = 1.8 V; R _{OUT} = 10 kΩ L_Detect, GND_Detect are connected with 10 kΩ to GND,	-	-	0.3	
MIC Rising Propagation Delay (insertion detection time)	t _{MICR}	From SW1 and SW2 ON, GND_Detect = 0 V, voltage on L_Detect drops to 0.9 V, to the time when MIC rises to 1.2 V and OUT falls below 0.3 V (refer to circuit below, R3 = 10K, C1 = 5 pF, MIC biased at 2.4 V via a 2.2K resistor)	-	1.5	2	μs
MIC Falling Propagation Delay (removal detection time)	t _{MICF}	From SW1 and SW2 ON, GND_Detect = 0 V, voltage on L_Detect rises to 0.9 V, to the time when MIC drops to 1.2 V and OUT rises above 0.3 V (refer to circuit below, R3 = 10K, C1 = 5 pF, MIC biased at 2.4 V via a 2.2K resistor)	-	350	500	ns
OUT Falling Propagation Delay	t _{OUTF}	From SW1 and SW2 ON, GND_Detect = 0 V, voltage on L_Detect drops to 0.9 V, to the time when MIC rises to 1.2 V and OUT falls below 0.3 V (refer to circuit below, R3 = 10K, C1 = 5 pF, MIC biased at 2.4 V via a 2.2K resistor)	-	1.4	2	μs
OUT Rising Propagation Delay	t _{OUTR}	From SW1 and SW2 ON, GND_Detect = 0 V, voltage on L_Detect rises to 0.9 V, to the time when MIC drops to 1.2 V and OUT rises above 0.3 V (refer to circuit below, R3 = 10K, C1 = 5 pF, MIC biased at 2.4 V via a 2.2K resistor)	-	350	500	ns
GND_Detect Capacitance	C _{GD}		-	-	5	pF

TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$, unless otherwise noted)

Quiescent Current vs. V_+

Quiescent Current vs. Temperature

Ear Jack In Current vs. V_+

Ear Jack In Current vs. Temperature

MIC On Resistance vs. V_+

MIC On Resistance vs. Temperature

TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$, unless otherwise noted)

MIC Leakage Current vs. V_{MIC}

MIC Leakage Current vs. Temperature

OUT Pulldown Resistance vs. I_{OUT}

OUT Pulldown Resistance vs. Temperature

OUT Pullup Resistance vs. I_{OUT}

OUT Pullup Resistance vs. Temperature

TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$, unless otherwise noted)

L_Detect Threshold Voltage vs. Temperature

GND_Detect Threshold Voltage vs. Temperature

L_Detect to OUT Propagation Delay vs. Temperature

GND_Detect to OUT Propagation Delay vs. Temperature

GND_Detect to MIC Propagation Delay vs. Temperature

L_Detect to MIC Propagation Delay vs. Temperature

TEST CIRCUIT

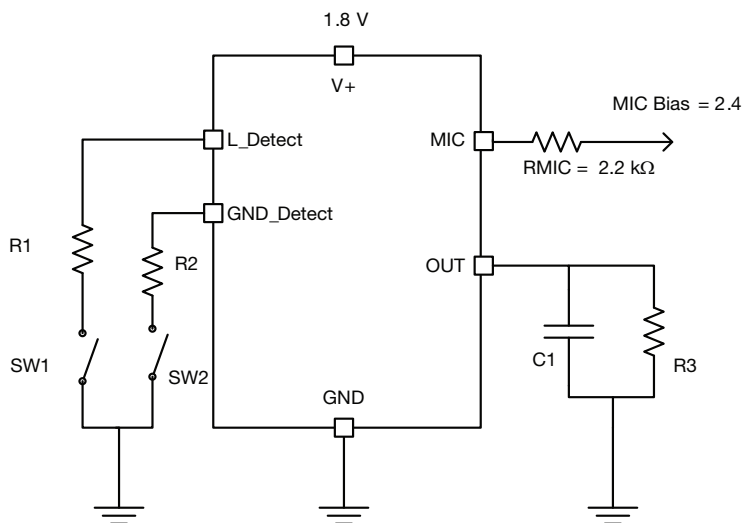


Fig. 4 - Test Circuit

TIMING DIAGRAM

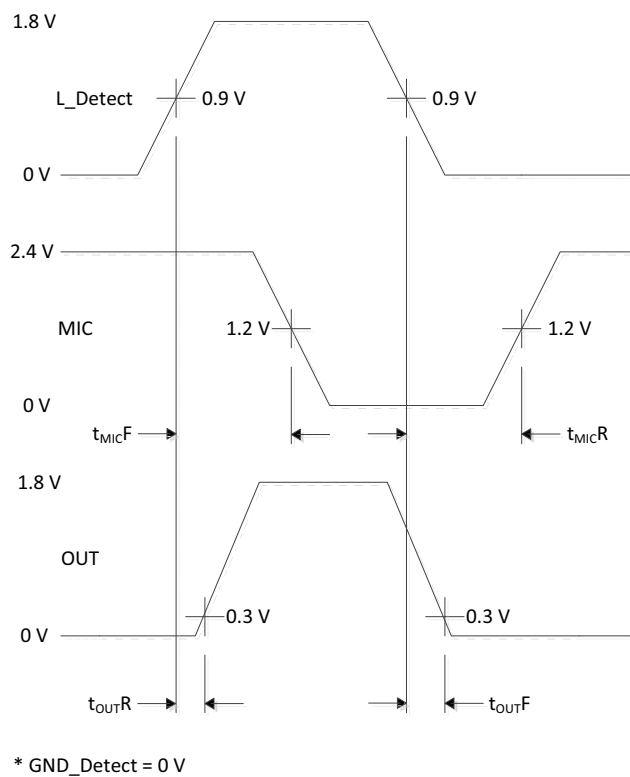
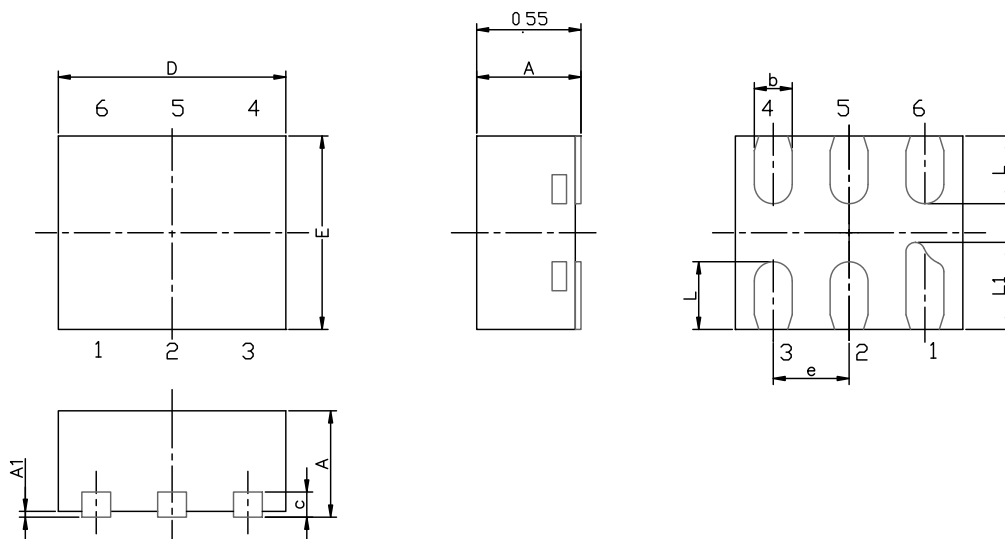


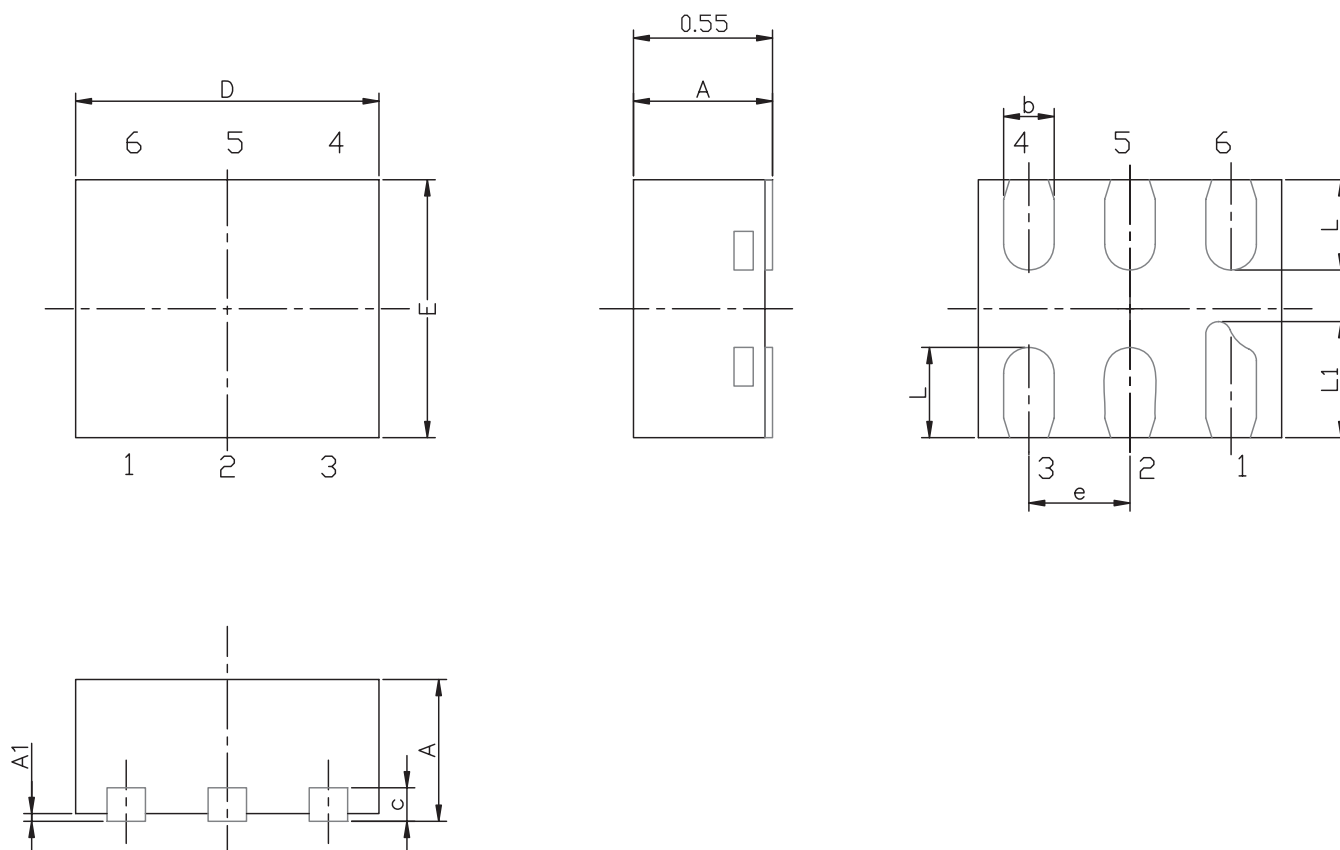
Fig. 5 - Timing Diagram

MINI QFN-6L CASE OUTLINE


DIM.	MILLIMETERS			INCHES		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
A	0.50	0.55	0.60	0.0197	0.0217	0.0236
A1	0	-	0.05	0	-	0.002
b	0.15	0.20	0.25	0.006	0.008	0.010
c	0.15 ref.			0.006 ref.		
D	1.15	1.20	1.25	0.045	0.047	0.049
E	0.95	1.00	1.05	0.037	0.039	0.041
e	0.40 BSC			0.016 BSC		
L	0.30	0.35	0.40	0.012	0.014	0.016
L1	0.40	0.45	0.50	0.016	0.018	0.020

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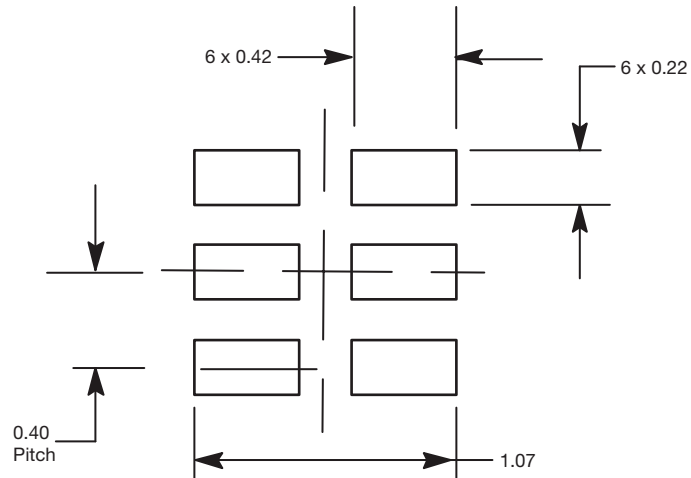
MINI QFN-6L CASE OUTLINE



DIM	MILLIMETERS			INCHES		
	MIN.	NAM.	MAX.	MIN.	NAM.	MAX.
A	0.50	0.55	0.60	0.0197	0.0217	0.0236
A1	0.00	-	0.05	0.000	-	0.002
b	0.15	0.20	0.25	0.006	0.008	0.010
c	0.15 REF			0.006 REF		
D	1.15	1.20	1.25	0.045	0.047	0.049
E	0.95	1.00	1.05	0.037	0.039	0.041
e	0.40 BSC			0.016 BSC		
L	0.30	0.35	0.40	0.012	0.014	0.016
L1	0.40	0.45	0.50	0.016	0.018	0.020

ECN T-07039-Rev. A, 12-Feb-07
DWG: 5958

RECOMMENDED MINIMUM PADS FOR MINI QFN 6L



Mounting Footprint
Dimensions in mm



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